TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIII)

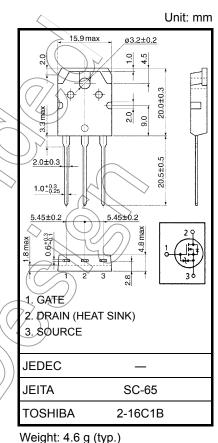
2SK2611

DC–DC Converter, Relay Drive and Motor Drive Applications

- Low drain-source ON-resistance $: RDS (ON) = 1.2 \Omega$ (typ.)
- High forward transfer admittance $|Y_{fs}| = 7.0 \text{ S (typ.)}$
- Low leakage current $: I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 720 \ V)$
- Enhancement-mode $: V_{th} = 2.0 \text{ to } 4.0 \text{ V} (V_{DS} = 10 \text{ V}, \text{ ID} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	900	V
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	900	Ň
Gate-source voltage		V _{GSS}	±30	\lor v
Drain current	DC (Note 1)	۱ _D	() ()	А
	Pulse (Note 1)	I _{DP}	27	A
Drain power dissipation	n (Tc = 25°C)	PD <	150	////
Single pulse avalanche energy (Note 2)		EAS	663	mJ
Avalanche current		TAR	9	А
Repetitive avalanche energy (Note 3)			15	Lm
Channel temperature	(Tch	150	°C)
Storage temperature ra	inge	T _{stg}	-55 to 150	°C



weight. 4.0 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Max	Unit
Thermal resistance, channel to case Rth (ch-c)	0.833	°C / W
Thermal resistance, channel to ambient Rth (ch-a)	50	°C / W

Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 15 mH, R_G = 25 Ω , I_{AR} = 9 A

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

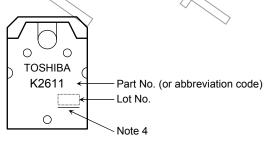
Electrical Characteristics (Ta = 25°C)

Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V	_	—	±10	μA
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	—		V
Drain cut-off cu	rrent	I _{DSS}	V_{DS} = 720 V, V_{GS} = 0 V	X	—	100	μA
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900	-	_	V
Gate threshold v	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	-7(4.0	V
Drain-source O	N-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$	2	1.2	1.4	Ω
Forward transfe	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 4 A	3.0	7.0	_	S
Input capacitance		C _{iss}			2040	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		45	_	pF
Output capacitance		C _{oss}		_	190	_	
Switching time	Rise time	tr	$v_{\rm GS} \stackrel{10V}{}_{\rm ov} \prod \stackrel{I_{\rm D}=4A}{}_{\rm v_{out}}$	- (25	\geq	
	Turn-on time	t _{on}	$\begin{array}{c} \mathbf{R}_{L} = \\ \mathbf{R}_{L} = $	C V	60) _	20
	Fall time	t _f	VDD ×400V	$\langle \gamma \rangle$	> 20	_	- ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_w = 10\mu s$		95	_	
Total gate charg plus gate-drain)		Qg		_	58	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 9 \text{ A}$	—	32	—	nC
Gate-drain ("mil	ller") Charge	Qgd		—	26	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)		_	_	_	9	А
Pulse drain reverse current (Note 1)	I _{DRP}	-	_		27	A
Forward voltage (diode)		I _{DR} = 9 A, V _{GS} = 0 V	_	-	-1.9	V
Reverse recovery time	trr	I _{DR} = 9 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs		1.6	_	μs
Reverse recovery charge	Qrr	$1DR = 9A, VGS = 0V, UDR / UI = 100A / \muS$		20	—	μC

Marking

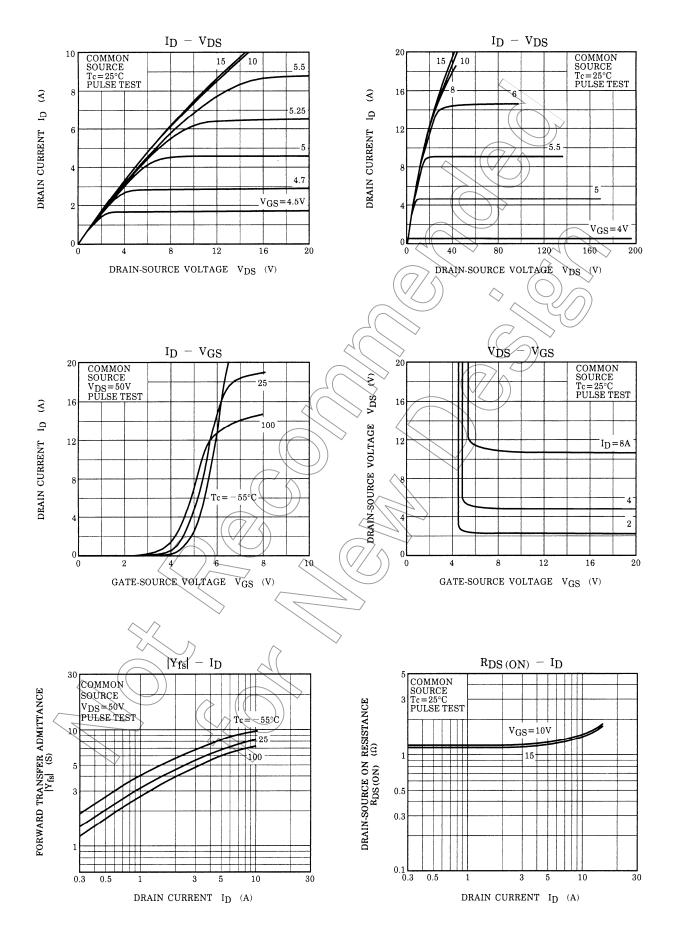


Note 4: A line under a Lot No. identifies the indication of product Labels.

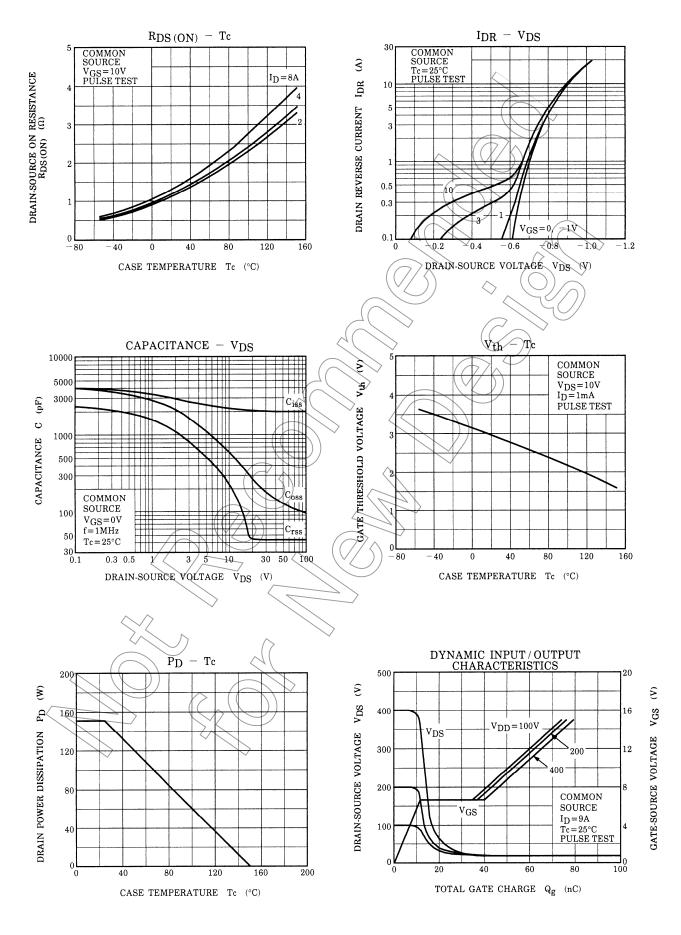
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

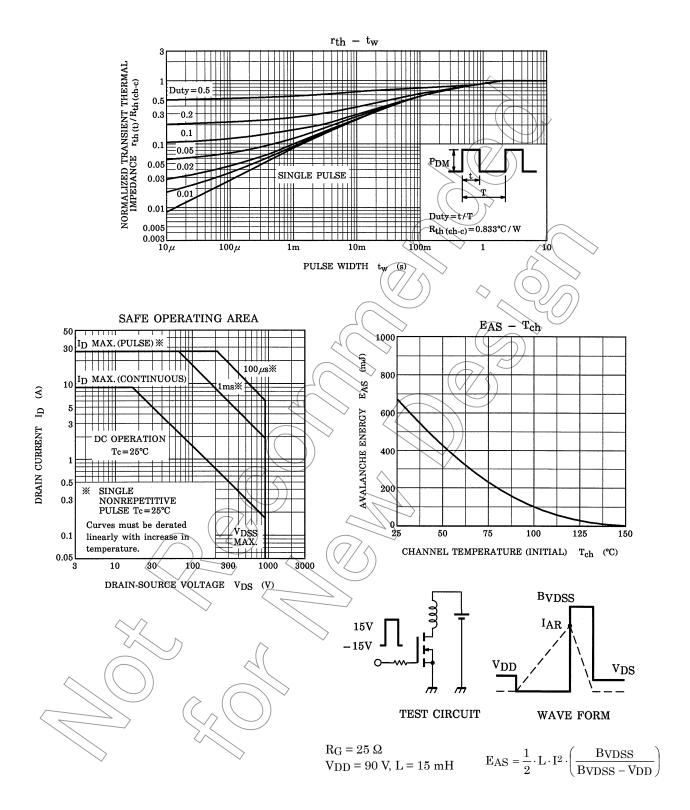
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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